

<b>FORM PTO-1449</b>				Atty. Docket No. <b>XA-9693A</b>		Appln. No. <b>10/701,497</b>	
<b><u>LIST OF DOCUMENTS CITED BY APPLICANT</u></b>							
				Applicant <b>Yoshitaka SASAGO et al.</b>			
				Filing Date <del>HEREWITH</del> <b>11-06-03</b>		Group <b>2822</b>	
<b>U.S. PATENT DOCUMENTS</b>							
Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
<i>JmJ</i>	AA	5,095,344	03/10/92	Harari (corrs. to JP 2694618)	357	23.5	
<i>JmJ</i>	AB	5,739,569	4/98	Chen	257	322	
<i>JmJ</i>	AC	5,773,863	6/98	Burr et al.	257	316	
<i>JmJ</i>	AD	6,492,690	12/02	Ueno et al.	257	316	
<i>JmJ</i>	AE	4,561,004	12/85	Kuo et al.	257	319	
<i>JmJ</i>	AF	4,745,083	5/88	Huie	257	316	
<i>JmJ</i>	AG	5,455,792	10/95	Yi	257	345	
<i>JmJ</i>	AH	5,640,032	6/97	Tomiooka	257	316	
	AI						
<b>FOREIGN PATENT DOCUMENTS</b>							
Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
	<del>AJ</del>	<del>2694618</del>	<del>09/12/97</del>	<del>Japan</del>			<del>No</del>
	<del>AK</del>	<del>9 321157</del>	<del>12/12/97</del>	<del>Japan</del>			<del>Abstract</del>
	AL						
	AM						
	AN						
	AO						
<b>OTHER (including author, title, date, pertinent pages, etc.)</b>							
	AP	<del>"Ohyo Butsuri" (or APPLIED PHYSICS), The Japan Society of Applied Physics, Vol. 65, No. 11, November 10, 1996, pp. 1114-1124.</del>					
	AQ	<del>K. Naruko et al., "A New Flash-Erase EEPROM Cell with a Sidewall Select-Gate on its Source Side", IBM, 1989, pp. 603-606.</del>					
	AR						
Examiner <b>T. M. Thomas</b>				Date Considered <b>12-01-05</b>			
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							